NSN 5961-01-317-5781

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Internal Configuration:
Field effect
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 breakdown voltage, collector-to-emitter, base open
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0